
	<h2>SI2341DS-T1-GE3</h2>
	<p><b>Hersteller-Teilenummer:</b> <a href="#">SI2341DS-T1-GE3</a></p> <p><b>Hersteller / Marke:</b> <a href="#">Electro-Films (EFI) / Vishay</a></p> <p><b>Teil der Beschreibung:</b> MOSFET P-CH 30V 2.5A SOT-23</p> <p><b>Datenblätter:</b>  <a href="#">SI2341DS-T1-GE3.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 64536 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	<a href="#">SI2341DS-T1-GE3</a>
Hersteller	<a href="#">Electro-Films (EFI) / Vishay</a>
Beschreibung	MOSFET P-CH 30V 2.5A SOT-23
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	64536 pcs Stock
detaillierte Beschreibung	P-Channel 30V 2.5A (Ta) 710mW (Ta) Surface Mount
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-236-3, SC-59, SOT-23-3
Supplier Device-Gehäuse	SOT-23-3 (TO-236)
Verlustleistung (max)	710mW (Ta)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	2.5A (Ta)
Rds On (Max) @ Id, Vgs	72 mOhm @ 2.8A, 10V
VGS (th) (Max) @ Id	3V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	15nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	400pF @ 15V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)

























SI2341DS-T1-GE3 ist neu im Original, Suche SI2341DS-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI2341DS-T1-GE3 Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage SI2341DS-T1-GE3: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>SI2343ADS-T1-GE3</b> V SI2343ADS-T1-GE3 V</p>	 <p><b>SI2342DS-T1-GE3</b> Vishay / Spectrol MOSFET N-CH 8V 6A SOT-23</p>	 <p><b>SI2342DS-T1-E3</b> Vishay / Siliconix MOSFET N-CH 8V 6A SOT-23</p>	 <p><b>SI2341DS-T1-E3</b> Vishay / Siliconix MOSFET P-CH 30V 2.5A SOT-23</p>
 <p><b>SI2341DS</b> VISHAY SI2341DS VISHAY</p>	 <p><b>SI2341DS-T1-E3</b> Electro-Films (EFI) / Vishay MOSFET P-CH 30V 2.5A SOT-23</p>	 <p><b>SI2342DS-T1-E3</b> VISHAY SI2342DS-T1-E3 VISHAY</p>	 <p><b>SI2341DS-T1-GE3</b> Vishay / Siliconix MOSFET P-CH 30V 2.5A SOT-23</p>

### heiße Teile

Mehr

 SI2333DS-T1-GE3	 SI2333DS-T1-GE3	 SI2334DS-T1-E3	 SI2334DS-T1-GE3	 SI2334DS-T1-GE3
 SI2335DS-T1	 SI2335DS-T1-E3	 SI2335DS-T1-E3	 SI2335DS-T1-GE3	 SI2335DS-T1-GE3
 SI2336DS-T1-E3	 SI2336DS-T1-GE3	 SI2336DS-T1-GE3	 SI2337DS	 SI2337DS-T1-E3
 SI2337DS-T1-E3	 SI2337DS-T1-GE3	 SI2337DS-T1-GE3	 SI2338DS-T1-E3	 SI2338DS-T1-GE3
 SI2338DS-T1-GE3	 SI2341DS	 SI2341DS-T1-E3	 SI2341DS-T1-E3	 SI2341DS-T1-GE3
 SI2342DS-T1-E3	 SI2342DS-T1-GE3	 SI2342DS-T1-GE3	 SI2343ADS-T1-GE3	 SI2343CDS
 SI2343CDS-T1-E3	 SI2343CDS-T1-GE3	 SI2343CDS-T1-GE3	 SI2343DS-T1-E3	 SI2343DS-T1-E3
 SI2343DS-T1-GE3	 SI2343DS-T1-GE3	 SI2344DS-E3	 SI2347DS-T1-GE3	 SI2347DS-T1-GE3
 SI2351DS-T1-E3	 SI2351DS-T1-E3	 SI2351DS-T1-GE3	 SI2351DS-T1-GE3	 SI2356DS-T1-GE3
 SI2356DS-T1-GE3	 SI2365EDS	 SI2365EDS-T1-GE3	 SI2365EDS-T1-GE3	 SI2366DS-T1-E3

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

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